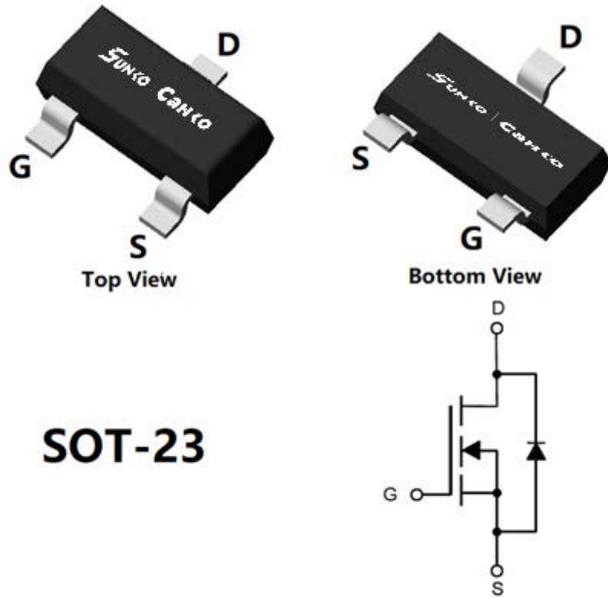


N-Channel Enhancement Mode Field Effect Transistor



SOT-23

Product Summary

- V_{DS} 30V
- I_D 5.6A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) <24mohm
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) <38mohm

General Description

- Trench Power LV MOSFET technology
- High density cell design for low $R_{DS(ON)}$
- High Speed switching
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Battery protection
- Load switch
- Power management

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | | Symbol | Limit | Unit |
|---|------------------|-----------------|----------|--------------|
| Drain-source Voltage | | V_{DS} | 30 | V |
| Gate-source Voltage | | V_{GS} | ± 20 | V |
| Drain Current | $T_A=25^\circ C$ | I_D | 5.6 | A |
| | $T_A=70^\circ C$ | | 4.5 | |
| Pulsed Drain Current ^A | | I_{DM} | 30 | A |
| Total Power Dissipation | $T_A=25^\circ C$ | P_D | 1.2 | W |
| | $T_A=70^\circ C$ | | 0.8 | |
| Thermal Resistance Junction-to-Ambient ^B | | $R_{\theta JA}$ | 104 | $^\circ C/W$ |
| Junction and Storage Temperature Range | | T_J, T_{STG} | -55~+150 | $^\circ C$ |

■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| SCL3404A | F2 | R4. | 3000 | 30000 | 120000 | 7" reel |

SCL3404A

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|-----------------------------------|---------------------|--|-----|-------|------|-------|
| Static Parameter | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250μA | 30 | | | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =30V, V _{GS} =0V | | | 1 | μA |
| Gate-Body Leakage Current | I _{GSS1} | V _{GS} =±20V, V _{DS} =0V | | | ±100 | nA |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | 1 | 1.5 | 2.2 | V |
| Static Drain-Source On-Resistance | R _{DS(on)} | V _{GS} =10V, I _D =5.6A | | 17 | 24 | mΩ |
| | | V _{GS} =4.5V, I _D =5A | | 26 | 38 | |
| Diode Forward Voltage | V _{SD} | I _S =5.6A, V _{GS} =0V | | | 1.2 | V |
| Dynamic Parameters | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =15V, V _{GS} =0V, f=1MHZ | | 526 | | pF |
| Output Capacitance | C _{oss} | | | 78 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 69 | | |
| Switching Parameters | | | | | | |
| Total Gate Charge | Q _g | V _{GS} =10V, V _{DS} =15V, I _D =5.6A | | 12.22 | | nC |
| Gate-Source Charge | Q _{gs} | | | 2.37 | | |
| Gate-Drain Charge | Q _{gd} | | | 2.31 | | |
| Reverse Recovery Charge | Q _{rr} | I _F =5.6A, di/dt=100A/us | | 1.28 | | ns |
| Reverse Recovery Time | t _{rr} | | | 16.5 | | |
| Turn-on Delay Time | t _{D(on)} | V _{GS} =10V, V _{DS} =15V, I _D =5.6A R _{GEN} =3Ω | | 5 | | ns |
| Turn-on Rise Time | t _r | | | 28.2 | | |
| Turn-off Delay Time | t _{D(off)} | | | 12.8 | | |
| Turn-off fall Time | t _f | | | 21.6 | | |

A. Pulse Test: Pulse Width ≤ 300us, Duty cycle ≤ 2%.

B. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design, while R_{θJA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

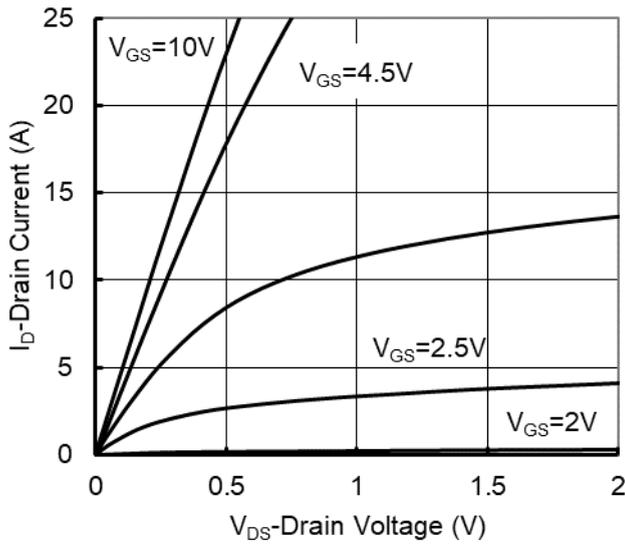


Figure1. Output Characteristics

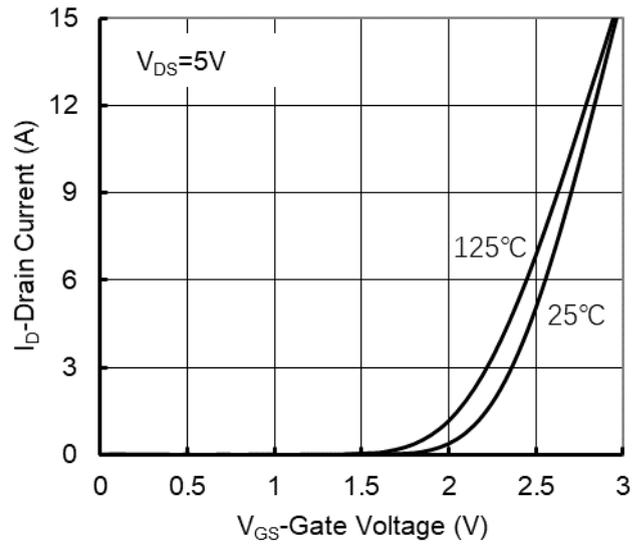


Figure2. Transfer Characteristics

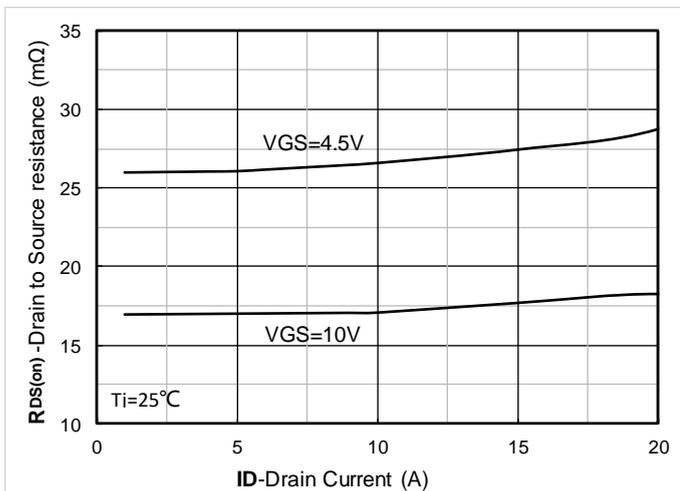


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

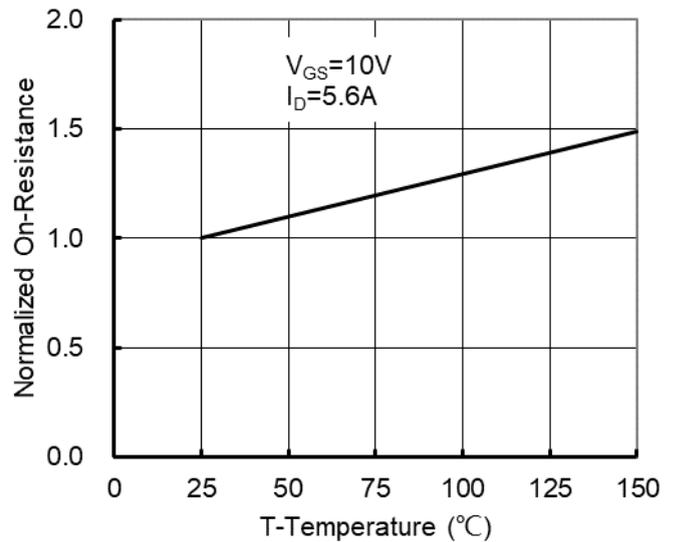


Figure 4: On-Resistance vs. Junction Temperature

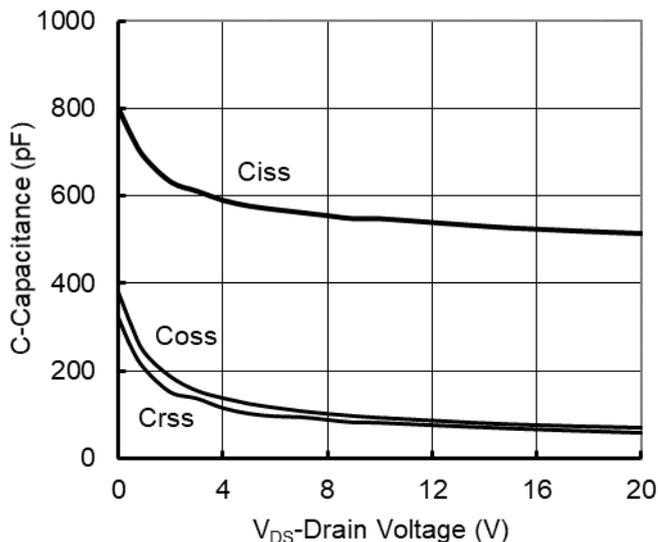


Figure5. Capacitance Characteristics

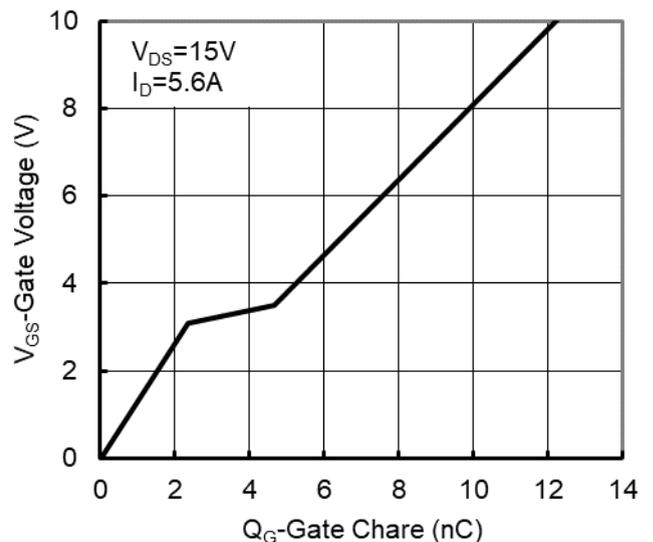


Figure6. Gate Charge

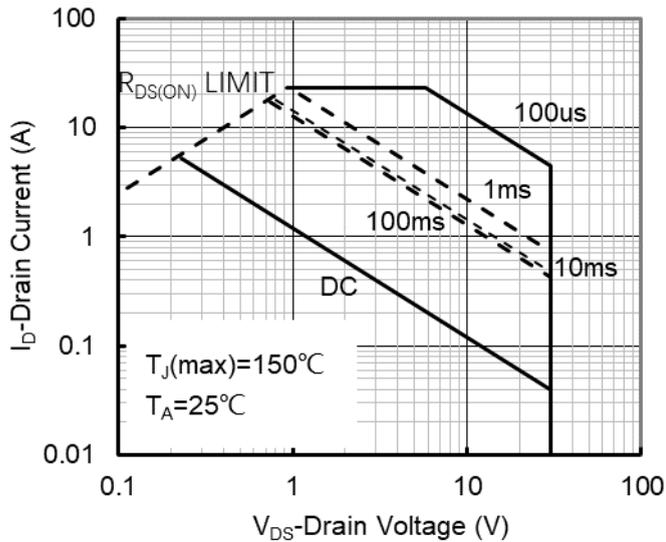


Figure7. Safe Operation Area

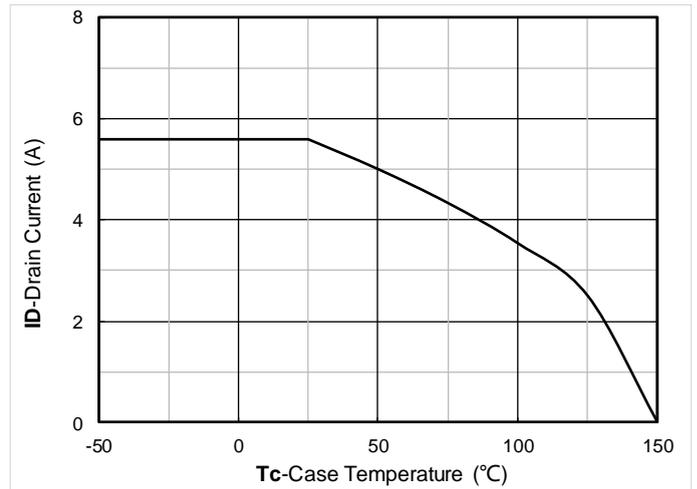


Figure8. Maximum Continuous Drain Current vs Ambient Temperature

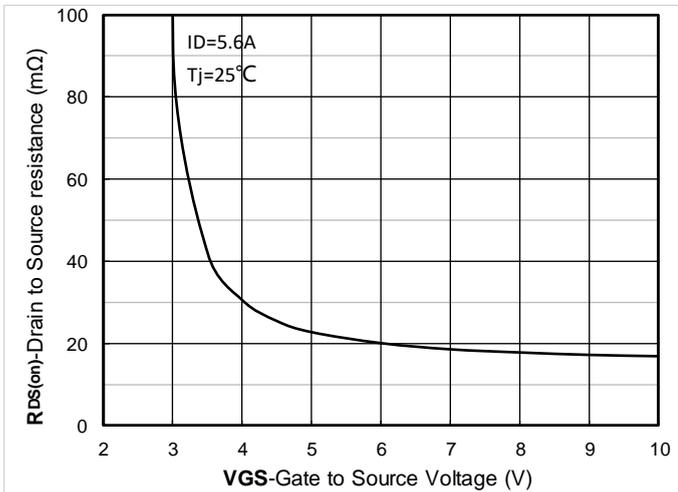


Figure 9. On-Resistance vs Gate to Source Voltage

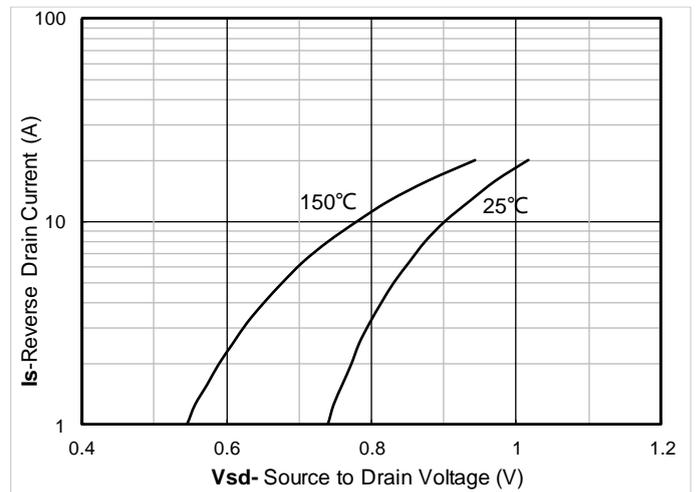


Figure 10. Forward characteristics of reverse diode

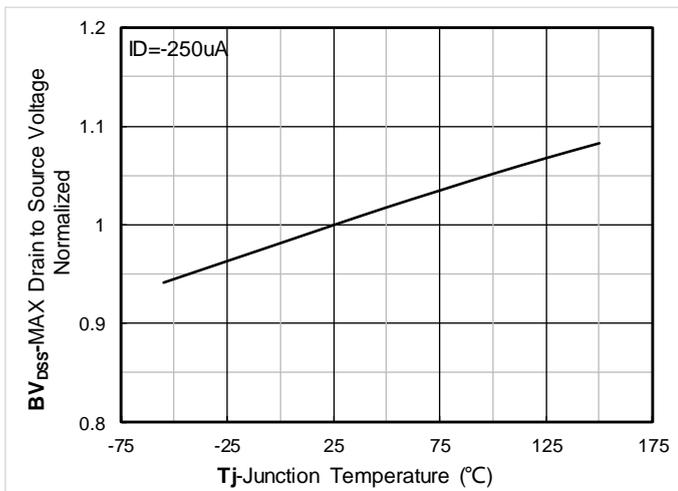


Figure 11. Normalized breakdown voltage

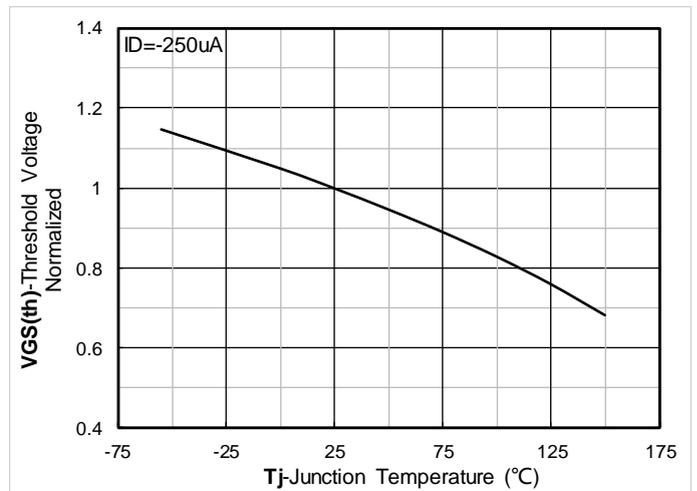


Figure 12. Normalized Threshold voltage

SCL3404A

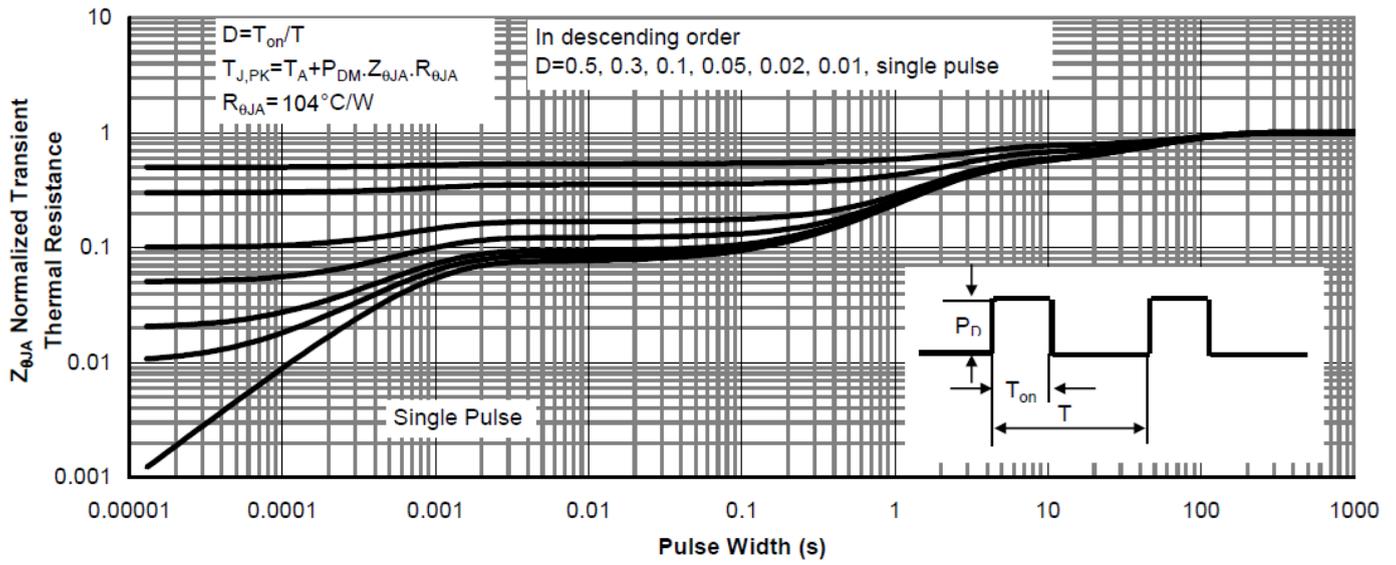
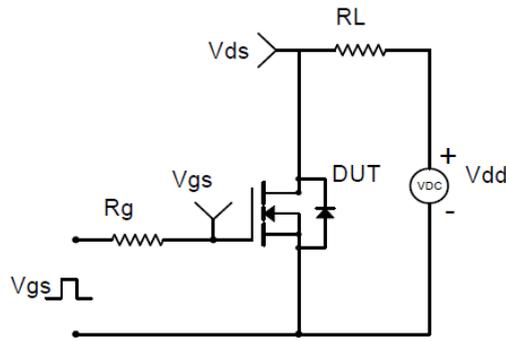
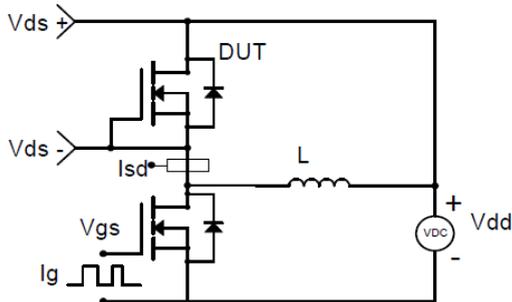


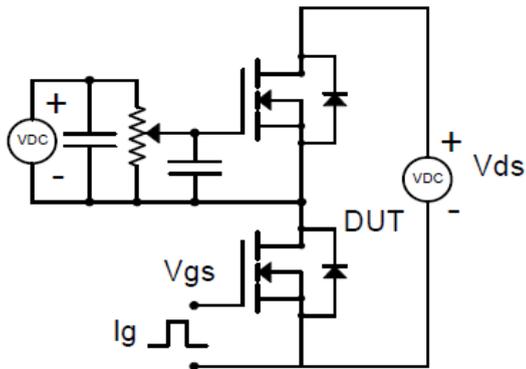
Figure13. Normalized Maximum Transient Thermal Impedance



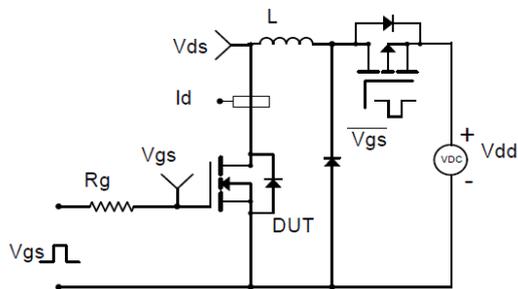
Resistive Switching Test Circuit & Waveforms



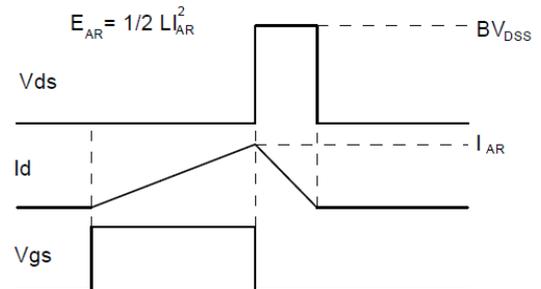
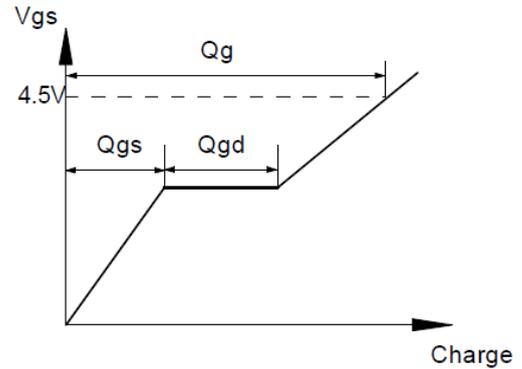
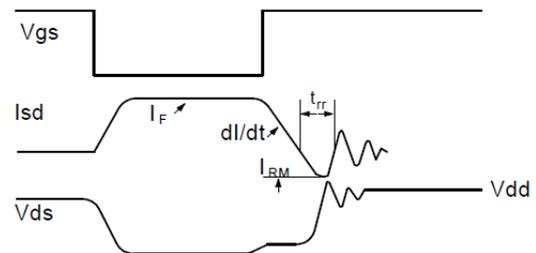
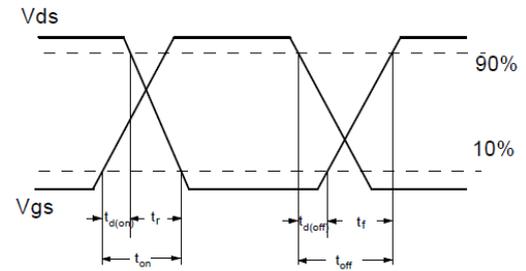
Diode Recovery Test Circuit & Waveforms



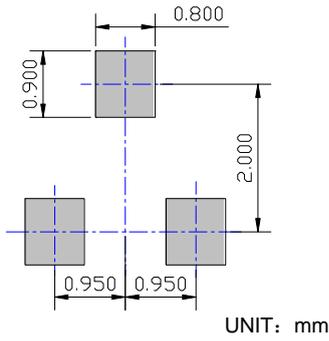
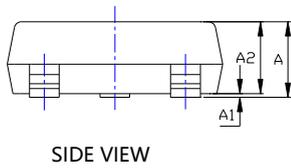
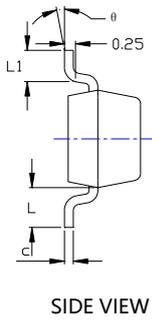
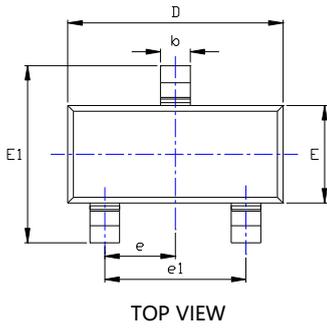
Gate Charge Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



■ SOT-23 Package information



SUGGESTED SOLDER PAD LAYOUT

| SYMBOL | DIMENSIONS | | | |
|--------|------------|-------|------------|-------|
| | INCHES | | Millimeter | |
| | MIN. | MAX. | MIN. | MAX. |
| A | 0.035 | 0.045 | 0.900 | 1.150 |
| A1 | 0.000 | 0.004 | 0.000 | 0.100 |
| A2 | 0.035 | 0.041 | 0.900 | 1.050 |
| b | 0.012 | 0.020 | 0.300 | 0.500 |
| c | 0.004 | 0.008 | 0.100 | 0.200 |
| D | 0.110 | 0.118 | 2.800 | 3.000 |
| E | 0.047 | 0.055 | 1.200 | 1.400 |
| E1 | 0.089 | 0.100 | 2.250 | 2.550 |
| e | 0.037TYP | | 0.950TYP | |
| e1 | 0.071 | 0.079 | 1.800 | 2.000 |
| L | 0.022REF | | 0.550REF | |
| L1 | 0.012 | 0.020 | 0.300 | 0.500 |
| θ | 0° | 8° | 0° | 8° |

NOTE:
 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
 2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
 3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

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